

**Polar™ HiPerFET™**  
**Power MOSFET**

**IXFA4N100P**  
**IXFP4N100P**

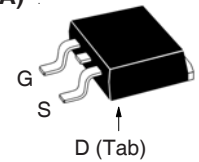
$V_{DSS} = 1000V$   
 $I_{D25} = 4A$   
 $R_{DS(on)} \leq 3.3\Omega$

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Rectifier

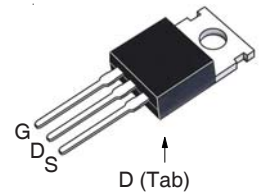


| Symbol        | Test Conditions                                                    | Maximum Ratings    |            |
|---------------|--------------------------------------------------------------------|--------------------|------------|
| $V_{DSS}$     | $T_J = 25^\circ C$ to $150^\circ C$                                | 1000               | V          |
| $V_{DGR}$     | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GS} = 1M\Omega$          | 1000               | V          |
| $V_{GSS}$     | Continuous                                                         | $\pm 30$           | V          |
| $V_{GSM}$     | Transient                                                          | $\pm 40$           | V          |
| $I_{D25}$     | $T_C = 25^\circ C$                                                 | 4                  | A          |
| $I_{DM}$      | $T_C = 25^\circ C$ , Pulse Width Limited by $T_{JM}$               | 8                  | A          |
| $I_A$         | $T_C = 25^\circ C$                                                 | 4                  | A          |
| $E_{AS}$      | $T_C = 25^\circ C$                                                 | 200                | mJ         |
| $dv/dt$       | $I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ | 10                 | V/ns       |
| $P_D$         | $T_C = 25^\circ C$                                                 | 150                | W          |
| $T_J$         |                                                                    | -55 ... +150       | $^\circ C$ |
| $T_{JM}$      |                                                                    | 150                | $^\circ C$ |
| $T_{stg}$     |                                                                    | -55 ... +150       | $^\circ C$ |
| $T_L$         | Maximum Lead Temperature for Soldering                             | 300                | $^\circ C$ |
| $T_{SOLD}$    | 1.6 mm (0.062in.) from Case for 10s                                | 260                | $^\circ C$ |
| $F_C$         | Mounting Force (TO-263)                                            | 10..65 / 2.2..14.6 | Nm/lb.in   |
| $M_d$         | Mounting Torque (TO-220)                                           | 1.13 / 10          | Nm/lb.in   |
| <b>Weight</b> | TO-263                                                             | 2.5                | g          |
|               | TO-220                                                             | 3.0                | g          |

TO-263 (IXFA)



TO-220 (IXFP)



G = Gate      D = Drain  
S = Source    Tab = Drain

**Features**

- International Standard Packages
- Low  $R_{DS(on)}$  and  $Q_G$
- Avalanche Rated
- Low Package Inductance
- Fast Intrinsic Rectifier

**Advantages**

- High Power Density
- Easy to Mount
- Space Savings

**Applications**

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

| Symbol       | Test Conditions<br>( $T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values |      |                           |
|--------------|---------------------------------------------------------------------|-----------------------|------|---------------------------|
|              |                                                                     | Min.                  | Typ. | Max.                      |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 250\mu A$                                    | 1000                  |      | V                         |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 250\mu A$                                | 3.0                   |      | 6.0 V                     |
| $I_{GSS}$    | $V_{GS} = \pm 30V$ , $V_{DS} = 0V$                                  |                       |      | $\pm 100$ nA              |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 125^\circ C$           |                       |      | 10 $\mu A$<br>750 $\mu A$ |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 0.5 \cdot I_{D25}$ , Notes 1                |                       |      | 3.3 $\Omega$              |

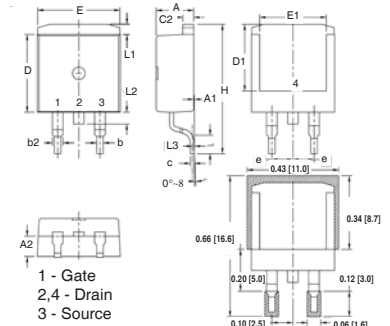
| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                                                                          | Characteristic Values |      |                    |
|--------------|----------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|--------------------|
|              |                                                                                                                                                    | Min.                  | Typ. | Max.               |
| $g_{fs}$     | $V_{DS} = 20\text{V}$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1                                                                                         | 1.8                   | 3.0  | S                  |
| $R_{Gi}$     | Gate Input Resistance                                                                                                                              |                       | 1.6  | $\Omega$           |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$                                                                                   |                       | 1456 | pF                 |
| $C_{oss}$    |                                                                                                                                                    |                       | 90   | pF                 |
| $C_{rss}$    |                                                                                                                                                    |                       | 16   | pF                 |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$<br>$R_G = 5\Omega$ (External) |                       | 24   | ns                 |
| $t_r$        |                                                                                                                                                    |                       | 36   | ns                 |
| $t_{d(off)}$ |                                                                                                                                                    |                       | 37   | ns                 |
| $t_f$        |                                                                                                                                                    |                       | 50   | ns                 |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$                                                                   |                       | 26   | nC                 |
| $Q_{gs}$     |                                                                                                                                                    |                       | 9    | nC                 |
| $Q_{gd}$     |                                                                                                                                                    |                       | 12   | nC                 |
| $R_{thJC}$   |                                                                                                                                                    |                       | 0.83 | $^\circ\text{C/W}$ |
| $R_{thCS}$   | TO-220                                                                                                                                             | 0.50                  |      | $^\circ\text{C/W}$ |

### Source-Drain Diode

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                            | Characteristic Values |      |               |
|----------|------------------------------------------------------------------------------------------------------|-----------------------|------|---------------|
|          |                                                                                                      | Min.                  | Typ. | Max.          |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                                 |                       |      | 4 A           |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$                                                          |                       |      | 16 A          |
| $V_{SD}$ | $I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1                                                          |                       |      | 1.3 V         |
| $t_{rr}$ | $I_F = 2\text{A}$ , $V_{GS} = 0\text{V}$ , $-di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 100\text{V}$ |                       |      | 300 ns        |
| $I_{RM}$ |                                                                                                      |                       | 5.30 | A             |
| $Q_{RM}$ |                                                                                                      |                       | 0.34 | $\mu\text{C}$ |

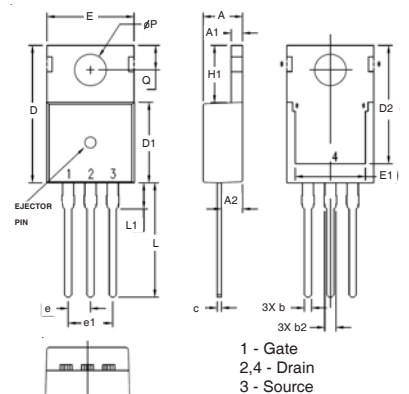
Note 1: Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

### TO-263 Outline



| SYM | INCHES   |      | MILLIMETER |       |
|-----|----------|------|------------|-------|
|     | MIN      | MAX  | MIN        | MAX   |
| A   | .170     | .185 | 4.30       | 4.70  |
| A1  | .000     | .008 | 0.00       | 0.20  |
| A2  | .091     | .098 | 2.30       | 2.50  |
| b   | .028     | .035 | 0.70       | 0.90  |
| b2  | .046     | .060 | 1.18       | 1.52  |
| C   | .018     | .024 | 0.45       | 0.60  |
| C2  | .049     | .060 | 1.25       | 1.52  |
| D   | .340     | .370 | 8.63       | 9.40  |
| D1  | .300     | .327 | 7.62       | 8.30  |
| E   | .380     | .410 | 9.65       | 10.41 |
| E1  | .270     | .330 | 6.86       | 8.38  |
| e   | .100 BSC |      | 2.54 BSC   |       |
| H   | .580     | .620 | 14.73      | 15.75 |
| L   | .075     | .105 | 1.91       | 2.67  |
| L1  | .039     | .060 | 1.00       | 1.52  |
| L2  | —        | .070 | —          | 1.77  |
| L3  | .010 BSC |      | 0.254 BSC  |       |

### TO-220 Outline

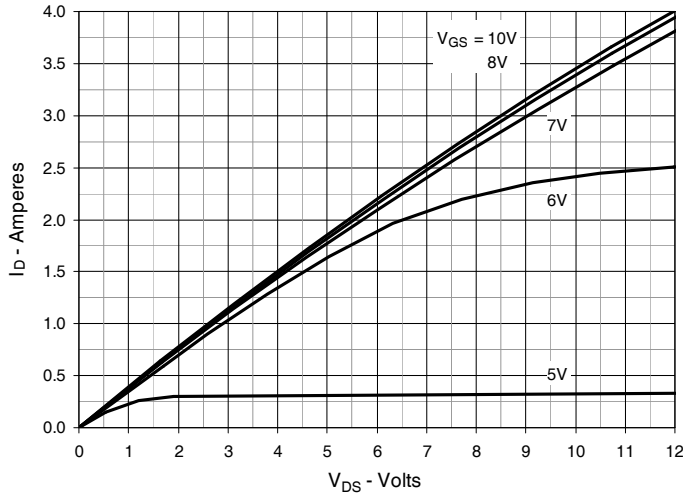


| SYM  | INCHES   |      | MILLIMETERS |       |
|------|----------|------|-------------|-------|
|      | MIN      | MAX  | MIN         | MAX   |
| A    | .169     | .185 | 4.30        | 4.70  |
| A1   | .047     | .055 | 1.20        | 1.40  |
| A2   | .079     | .106 | 2.00        | 2.70  |
| b    | .024     | .039 | 0.60        | 1.00  |
| b2   | .045     | .057 | 1.15        | 1.45  |
| c    | .014     | .026 | 0.35        | 0.65  |
| D    | .587     | .626 | 14.90       | 15.90 |
| D1   | .335     | .370 | 8.50        | 9.40  |
| (D2) | .500     | .531 | 12.70       | 13.50 |
| E    | .382     | .406 | 9.70        | 10.30 |
| (E1) | .283     | .323 | 7.20        | 8.20  |
| e    | .100 BSC |      | 2.54 BSC    |       |
| e1   | .200 BSC |      | 5.08 BSC    |       |
| H1   | .244     | .268 | 6.20        | 6.80  |
| L    | .492     | .547 | 12.50       | 13.90 |
| L1   | .110     | .154 | 2.80        | 3.90  |
| ØP   | .134     | .150 | 3.40        | 3.80  |
| Q    | .106     | .126 | 2.70        | 3.20  |

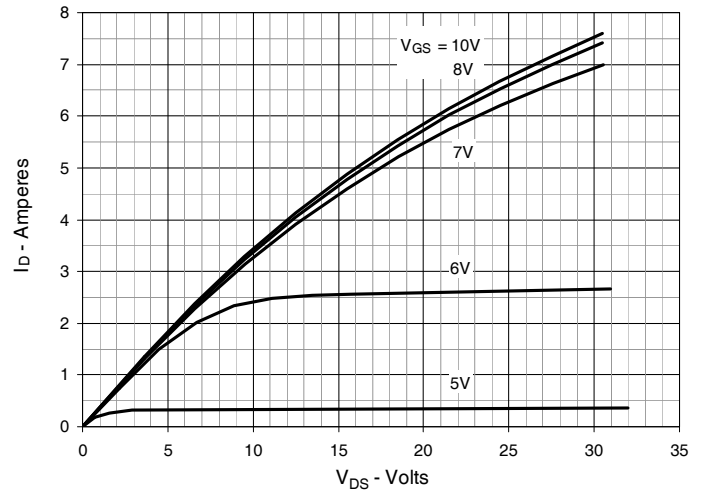
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|                                                                                  |           |           |           |           |             |             |             |             |             |             |
|----------------------------------------------------------------------------------|-----------|-----------|-----------|-----------|-------------|-------------|-------------|-------------|-------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665   | 6,404,065B1 | 6,683,344   | 6,727,585   | 7,005,734B2 | 7,157,338B2 |
|                                                                                  | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123B1 | 6,534,343   | 6,710,405B2 | 6,759,692   | 7,063,975B2 |             |
|                                                                                  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728B1 | 6,583,505   | 6,710,463   | 6,771,478B2 | 7,071,537   |             |

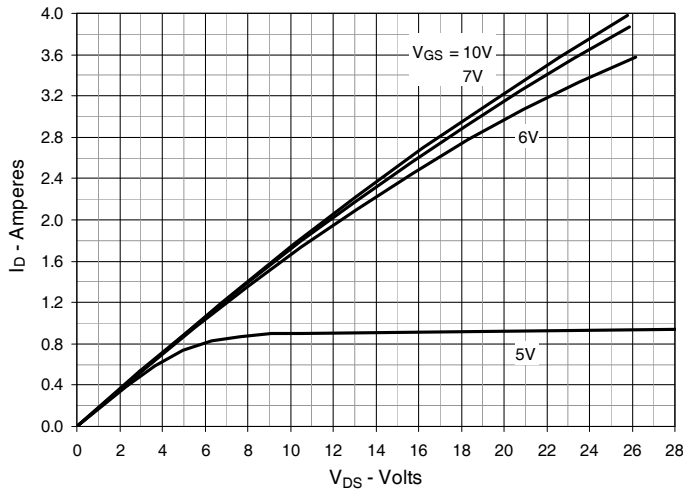
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



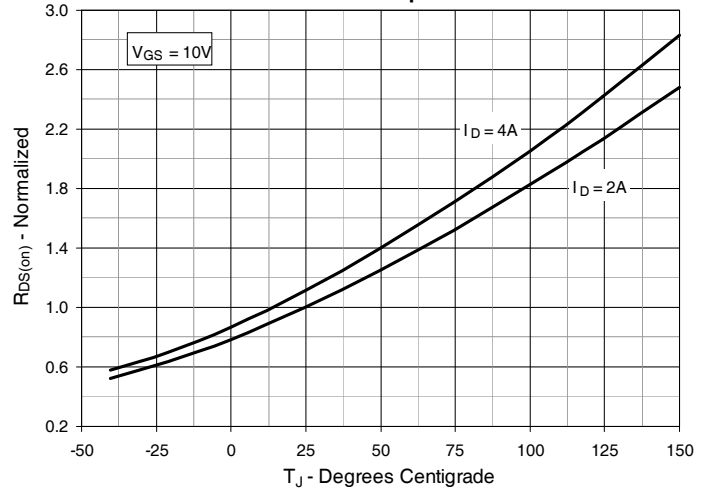
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



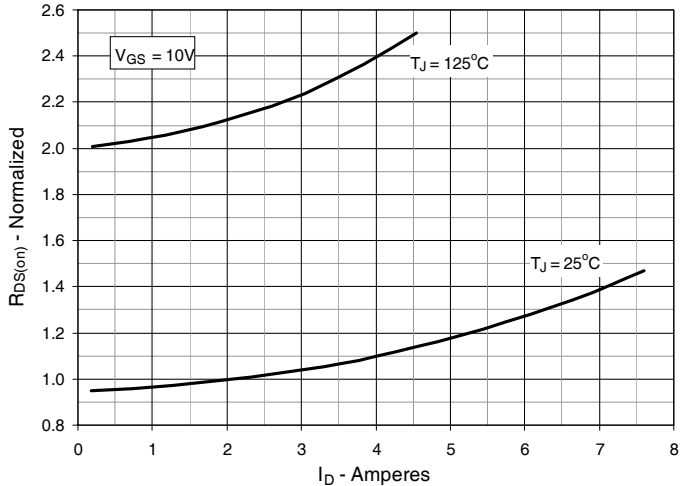
**Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$**



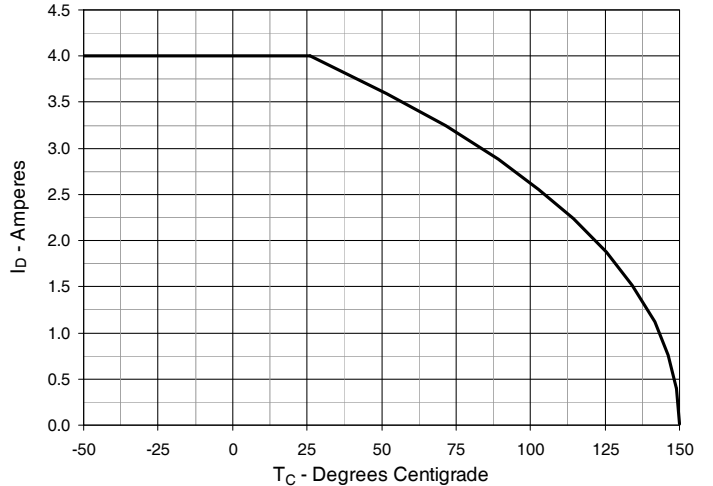
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 2\text{A}$  Value vs. Junction Temperature**



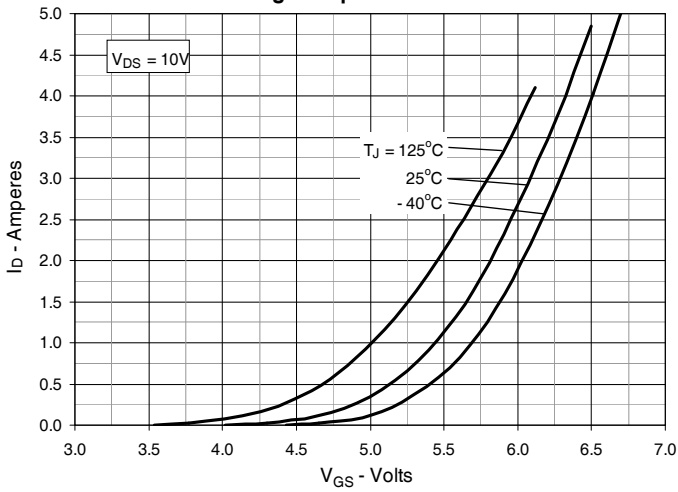
**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 2\text{A}$  Value vs. Drain Current**



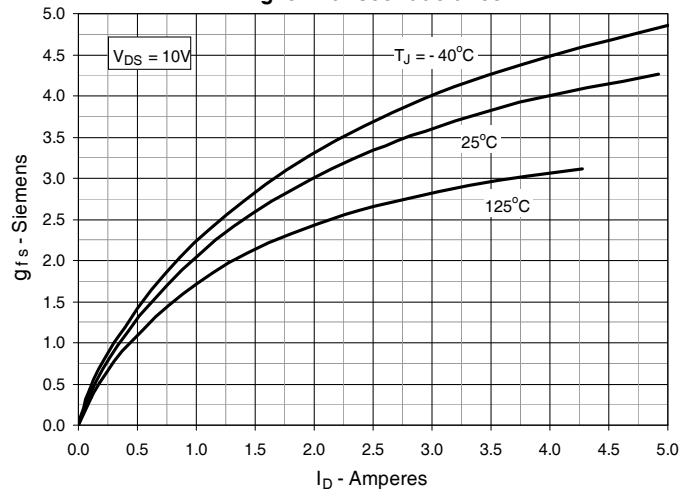
**Fig. 6. Maximum Drain Current vs. Case Temperature**



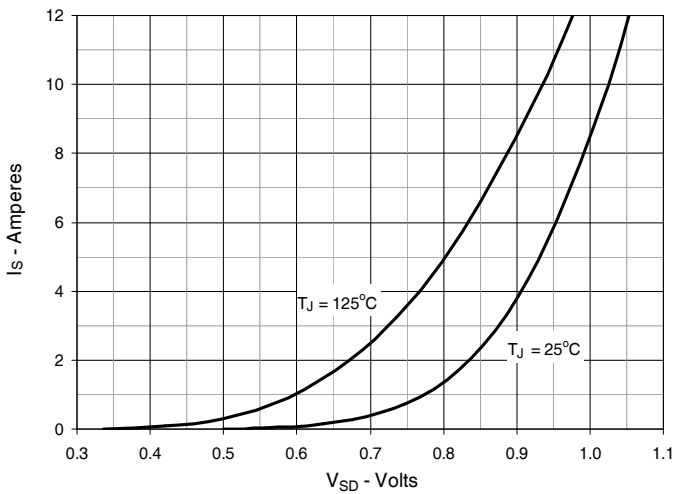
**Fig. 7. Input Admittance**



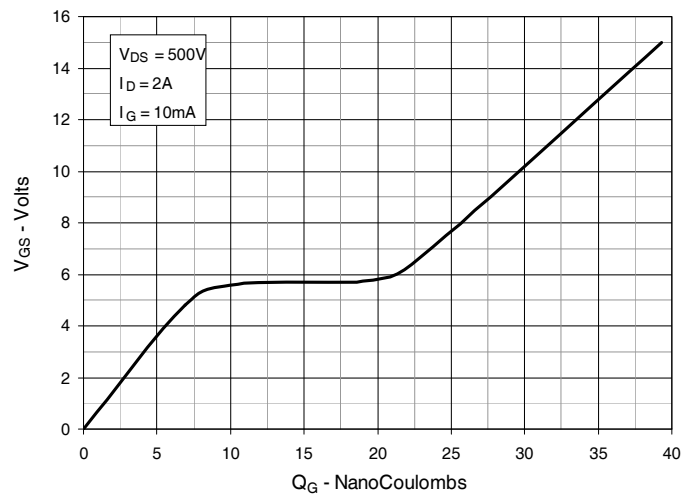
**Fig. 8. Transconductance**



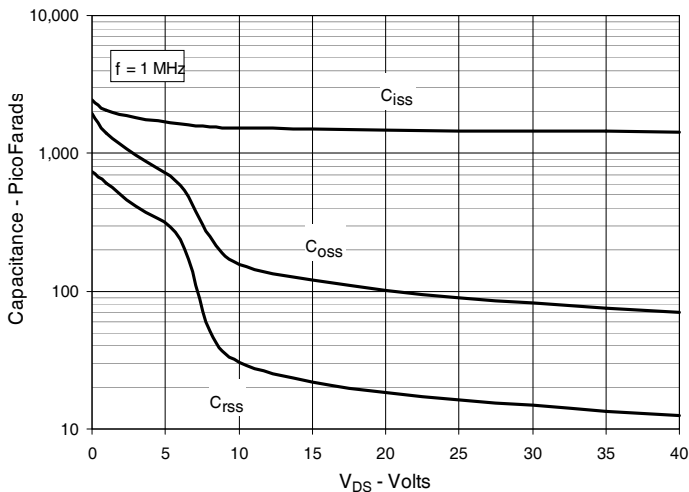
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



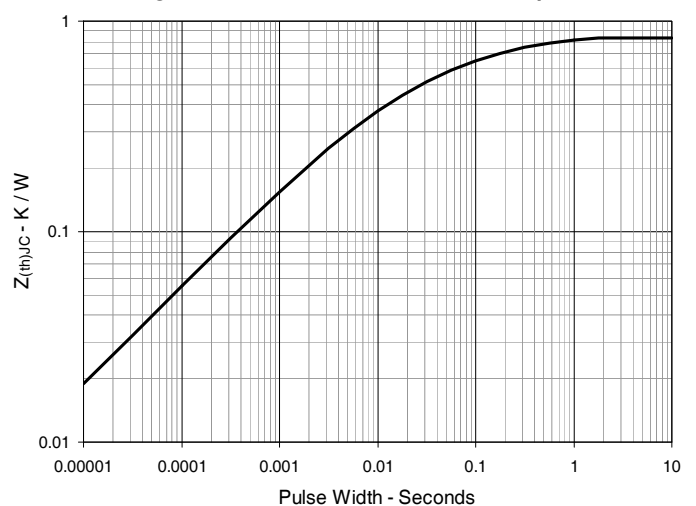
**Fig. 10. Gate Charge**



**Fig. 11. Capacitance**



**Fig. 12. Maximum Transient Thermal Impedance**





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